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IEEE WMED 2019 Table of Contents

| | |
|-----------------------------------------------------------------------------------------------------|-------|
| Welcome to the IEEE WMED 2019 | v |
| Organizing Committee | vi |
| Technical Program | vii |
| High School Program | x |
| Keynote Address | |
| DRAM Scaling Challenges and Future | xiii |
| Invited Talks | |
| Does CDM ESD Protection Really Work? | xiv |
| <i>Albert Wang</i> | |
| Neurocomputing and Hardware Security with Memory Devices | xv |
| <i>Dmitri B. Strukov</i> | |
| Phase-Change Materials for Storage Class Memory: Novel Bonds at Work | xvii |
| <i>M. Wuttig</i> | |
| Bridging Mechanics and Electrochemistry: Experiments and Modeling on Battery Materials | xviii |
| <i>Kejie Zhao</i> | |
| Keynote Talk | |
| Nanoelectronics and Heterogeneous Integration with 2D Materials | xix |
| <i>Eric Pop</i> | |
| Invited Talks | |
| Innovations in Device Packaging: Glass, Lasers, Materials, and Integration | xx |
| <i>Steve Groothuis</i> | |
| Emerging Materials for Additive Manufacturing of Flexible Hybrid Sensors | xxi |
| <i>David Estrada</i> | |
| Phase Transition Materials Assisted Energy Efficient CMOS Design | xxii |
| <i>Jaydeep Kulkarni</i> | |
| Invited Contribution | |
| Does CDM ESD Protection Really Work? | xxv |
| <i>Mengfu Di, Han Wang, Feilong Zhang, Cheng Li, Zijin Pan, and Albert Wang</i> | |

| | |
|----------------------------------------------------------------------------------------------------------------------------------------|------|
| Contributed Paper Sessions | xxix |
| Numerical Study of Non-Circular Pillar Effect in 3D-NAND Flash Memory Cells | 1 |
| <i>Albert Fayrushin, Haitao Liu, Aurelio Mauri, Gianpietro Carnevale, Hyejin Cho, and Duo Mao</i> | |
| Metal-Site Dopants in Two-Dimensional Transition Metal Dichalcogenides | 5 |
| <i>I. Williamson, M. Lawson, S. Li, Y. Chen, and L. Li</i> | |
| Structural and Magnetic Properties of CoPd Alloys for Non-Volatile Memory Applications | 10 |
| <i>Joseph B. Abugri, Billy D. Clark, Sujan Budhathoki, Pieter B. Visscher, Adam Hauser, and Subhadra Gupta</i> | |
| 3D Simulation Technique to Predict Failure of Photo Marks Interaction | 15 |
| <i>Radhakrishna Kotti</i> | |
| Deep Learning for Industrial IoT-Empowered Processes: Methods, Applications, Infrastructure, and Practical Considerations | P IC |
| <i>Sujata Butte, Aleksandar Vakanski, and Min Xian</i> | |
| Resistance-Based Embedded Non-Volatile Memories as Synaptic Devices in Spiking Neural Networks | 23 |
| <i>Foroozan S. Koushan and Sung-Mo Steve Kang</i> | |
| Three Dimensional Time Domain Simulation of the Quantum Magnetic Susceptibility | 27 |
| <i>Jennifer Houle, Dennis Sullivan, Ethan Crowell, Sean Mossman, and Mark G. Kuzyk</i> | |
| An Optically Reconfigurable Gate Array Workable Under a Strong Gamma Radiation Environment | 32 |
| <i>Shinya Fujisaki, Takumi Fujimori, and Minoru Watanabe</i> | |
| Poster Session | 37 |
| Atomic Layer Deposition of Gallium Phosphide | 39 |
| <i>Sara Kuraitis and Elton Graugnard</i> | |
| Investigation of Molybdenum Disulfide Atomic Layer Deposition on Dielectric Surfaces | 40 |
| <i>Steven Letourneau, Jake Soares, Anil U. Mane, Jeffrey W. Elam, and Elton Graugnard</i> | |
| Dependency of RGB and Metrology Data Correlation on Wafer Alignment | 41 |
| <i>Swetha Barkam, James Cultra, Zhenyu Bo, and Sri Sai Vegunta</i> | |
| Scanning Probe Microscopy for Nanoscale Characterization of Electrical and Magnetic Properties | 41 |
| <i>Olivia Maryon</i> | |
| Author Index | 42 |
| Sponsors | 44 |